NSN 5961-01-132-1442

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View Online at https://aerobasegroup.com/nsn/5961-01-132-1442 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Terminal Length:** 0.360 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 40.00 amperes source cutoff current and 80.00 milliamperes source cutoff current **Power Rating Per Characteristic:**

50.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

88818-a532a031 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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